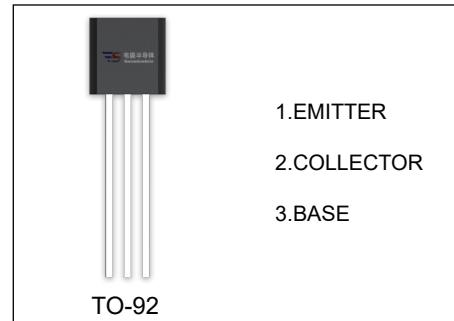


BC350 TRANSISTOR (PNP)

FEATURES

- General Purpose Switching and Amplification.



ORDERING INFORMATION

Part Number	Package	Packing Method	Pack Quantity
BC350	TO-92	Bulk	1000pcs/Bag
BC350-TA	TO-92	Tape	2000pcs/Box

MAXIMUM RATINGS ($T_a=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	-50	V
V_{CEO}	Collector-Emitter Voltage	-45	V
V_{EBO}	Emitter-Base Voltage	-5	V
I_c	Collector Current -Continuous	-0.1	A
P_c	Collector Power Dissipation	0.3	W
$R_{\theta JA}$	Thermal Resistance From Junction To Ambient	416	°C/W
T_J, T_{stg}	Operation Junction and Storage Temperature Range	-55~+150	°C

T_a=25 °C unless otherwise specified

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	I _C = -0.1mA, I _E =0	-50			V
Collector-emitter breakdown voltage	V _{(BR)CEO}	I _C =-1mA, I _B =0	-45			V
Emitter-base breakdown voltage	V _{(BR)EBO}	I _E =-0.1mA, I _C =0	-5			V
Collector cut-off current	I _{CBO}	V _{CB} =-50V, I _E =0			-0.1	µA
Collector cut-off current	I _{CEO}	V _{CE} =-35V, I _B =0			-0.1	µA
Emitter cut-off current	I _{EBO}	V _{EB} =-3V, I _C =0			-0.1	µA
DC current gain	h _{FE}	V _{CE} =-5V, I _C =-2mA	40		450	
Collector-emitter saturation voltage	V _{CE(sat)}	I _C =-10mA, I _B =-1mA			-0.3	V
Base-emitter saturation voltage	V _{BE(sat)}	I _C =-10mA, I _B =-1mA			-1	V
Transition frequency	f _T	V _{CE} =-5V, I _C =-10mA, f=30MHz	125			MHz